# 2SC5814, 2SC5815, 2SC5816, 2SC5817

For Low Frequency Amplify Application
Silicon NPN Epitaxial Type

## **DESCRIPTION**

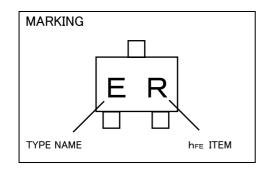
2SC5814, 2SC5815, 2SC5816, 2SC5817 is a super mini package silicon NPN epitaxial type transistor. It is designed for low frequency voltage amplify application.

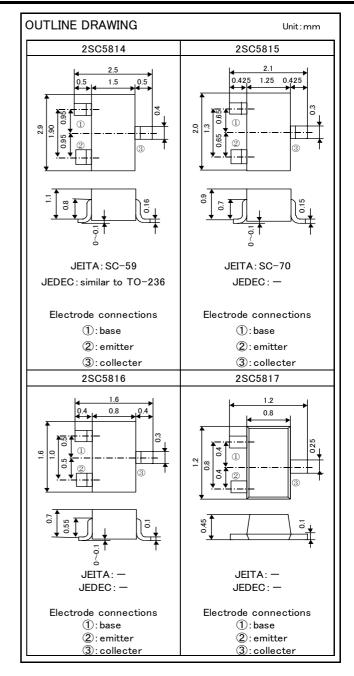
#### **FEATURE**

- Facilitates miniaturization and high-density mounting
- Excellent linearity of DC forward current gain
- ●Low collecter to emitter saturation voltage VcE(sat)=0.3V max (@Ic=30mA,IB=1.5mA)

#### **APPLICATION**

For hybrid IC , small type machine low frequency voltage amplify application





## MAXIMUM RATINGS (Ta=25°C)

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SYMBOL	PARAMETER	RATINGS				UNIT
		2SC5814	2SC5815	2SC5816	2SC5817	CIVIT
V <sub>CBO</sub>	Collector to Base voltage	60			٧	
V <sub>EBO</sub>	Emitter to Base voltage	6			٧	
V <sub>CEO</sub>	Collector to Emitter voltage	60			٧	
I <sub>C</sub>	Collector current	125			mA	
P <sub>c</sub>	Collector dissipation	15	50	125	100	mW
T <sub>j</sub>	Junction temperature	+125			°C	
T <sub>stg</sub>	Storage temperature	-55 <b>∼</b> +125			°C	

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# ELECTRICAL CHARACTERISTICS (Ta=25°C)

SYMBOL	PARAMETER	TEST CONDITIONS	TEST CONDITIONS	LIMITS			UNIT
		TEST CONDITIONS	TEST CONDITIONS		TYP	MAX	UNIT
V <sub>(BR)CEO</sub>	C to E break down voltage	I <sub>c</sub> =100uA, R <sub>BE</sub> =∞		60			٧
I <sub>CBO</sub>	Collector cut off current	$V_{CB}$ =60V, I $_{E}$ =0mA				0.5	μΑ
<b>І</b> ЕВО	Emitter cut off current	V <sub>EB</sub> =4V, I c=0mA				0.5	μΑ
hfe *	DC forward current gain	VcE=6V, Ic=1mA		120		560	-
hfE	DC forward current gain	VcE=6V, Ic=0.1mA		70			-
V <sub>CE(sat)</sub>	C to E saturation voltage	Ic=30mA, I <sub>B</sub> =1.5mA				0.3	٧
fτ	Gain band width product	Vce=6V, Ie=-10mA			200		MHz
Cob	Collector output capacitance	VcB=6V, IE=0mA, f=1MHz			1.5		pF

<sup>\*</sup> It shows  $h_{\text{FE}}$  classification in right table.

Item	Q	R	S
h <sub>FE</sub>	120~270	180~390	180~390
Marking	EQ	ER	ES

Item	E	F	
h <sub>FE</sub>	150~300	250~500	
Marking	EE	EF	



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